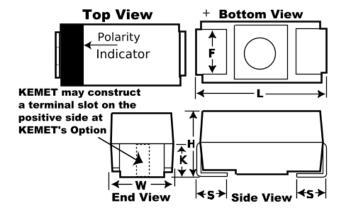


T498A685M004ZTE3K9

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 6.8 uF, 20%, 4 VDC, SMD, Molded, High Temperature, N/A, 3.9 Ohms, 3216, Height Max = 1.8mm



Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Н	1.6mm +/-0.2mm
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
К	1.3mm TYP

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

General Information		
Series	B45196P	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, High Temperature	
Features	High Temperature	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45196P0685M109.	

Specifications	
Capacitance	6.8 uF
Capacitance Tolerance	20%
Voltage DC	4 VDC (85C), 3.19 VDC (125C), 2.68 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	3.9 Ohms (100kHz)
Leakage Current	0.5 uA

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